

# **BUK9M67-60EL**

Single N-channel 60 V, 44 mOhm logic level MOSFET in LFPAK33 using Enhanced SOA technology 7 April 2022

Product data sheet

## 1. General description

Single, logic level, N-channel MOSFET in LFPAK33 using Application specific (ASFET) Enhanced SOA technology. This product has been designed and qualified to AEC-Q101 for use in linear mode in airbag applications.

## 2. Features and benefits

- Fully automotive qualified to AEC-Q101 at 175 °C
- Enhanced SOA technology for improved linear mode performance
- LFPAK copper clip package technology:
  - · High robustness and current handling capability
  - Gull wing leads for easy AOI inspection and exceptional board level reliability •

## 3. Applications

- 12 V automotive systems
- Airbag squib voltage regulator MOSFET

## 4. Quick reference data

#### Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>DS</sub>	drain-source voltage	25 °C ≤ T <sub>j</sub> ≤ 175 °C		-	-	60	V
I <sub>D</sub>	drain current	V <sub>GS</sub> = 10 V; T <sub>mb</sub> = 25 °C; <u>Fig. 2</u>	[1]	-	-	20	А
P <sub>tot</sub>	total power dissipation	T <sub>mb</sub> = 25 °C; <u>Fig. 1</u>		-	-	45	W
Static chara	acteristics	·		·			
R <sub>DSon</sub>	drain-source on-state resistance	V <sub>GS</sub> = 10 V; I <sub>D</sub> = 5 A; T <sub>j</sub> = 25 °C; <u>Fig. 13</u>		24.5	35	43.8	mΩ
Dynamic ch	naracteristics	·					
Q <sub>GD</sub>	gate-drain charge	$I_D = 5 \text{ A}; V_{DS} = 48 \text{ V}; V_{GS} = 4.5 \text{ V};$ $T_j = 25 \text{ °C}; \frac{\text{Fig. 15}}{\text{Fig. 16}}; \frac{16}{\text{Fig. 16}}$		-	3.1	6.2	nC

20 A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, [1] thermal design and operating temperature.

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## 5. Pinning information

Table 2	. Pinning info	rmation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S	source		
2	S	source		D
3	S	source		
4	G	gate		() [马本)
mb	D	Mounting base; connected to drain	LFPAK33 (SOT1210)	mbb076 S

## 6. Ordering information

#### Table 3. Ordering information

Type number	Package					
	Name	Description	Version			
BUK9M67-60EL		Plastic, single ended surface mounted package (LFPAK33); 8 leads; 0.65 mm pitch	SOT1210			

## 7. Marking

Table 4.	Marking	codes

Type number	Marking code
BUK9M67-60EL	9676EL

## 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Tj = 25 °C unless otherwise stated.

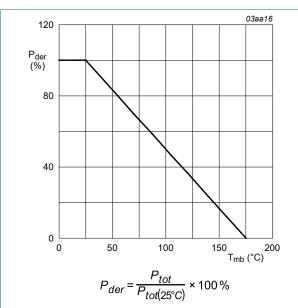
Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>DS</sub>	drain-source voltage	25 °C ≤ T <sub>j</sub> ≤ 175 °C		-	60	V
V <sub>GS</sub>	gate-source voltage	DC; T <sub>j</sub> ≤ 175 °C		-10	10	V
P <sub>tot</sub>	total power dissipation	T <sub>mb</sub> = 25 °C; <u>Fig. 1</u>		-	45	W
ID	drain current	V <sub>GS</sub> = 10 V; T <sub>mb</sub> = 25 °C; <u>Fig. 2</u>	[1]	-	20	A
		V <sub>GS</sub> = 10 V; T <sub>mb</sub> = 100 °C; <u>Fig. 2</u>		-	15	А
I <sub>DM</sub>	peak drain current	pulsed; $t_p \le 10 \ \mu$ s; $T_{mb} = 25 \ ^{\circ}$ C; <u>Fig. 3;</u> Fig. 4		-	85	A
T <sub>stg</sub>	storage temperature			-55	175	°C
Tj	junction temperature			-55	175	°C
Source-drai	n diode					
I <sub>S</sub>	source current	T <sub>mb</sub> = 25 °C		-	20	А
I <sub>SM</sub>	peak source current	pulsed; $t_p \le 10 \ \mu s$ ; $T_{mb} = 25 \ ^{\circ}C$		-	85	А
Avalanche r	uggedness	1				_
E <sub>DS(AL)S</sub>	non-repetitive drain- source avalanche energy	$ \begin{array}{l} I_{D} = 16.2 \text{ A}; \ V_{sup} \leq \ 60 \text{ V}; \ R_{GS} = 50 \ \Omega; \\ V_{GS} = 10 \text{ V}; \ T_{j(init)} = 25 \ ^{\circ}\text{C}; \ unclamped; \\ t_{p} = 22 \ \mu s; \ \underline{Fig. \ 5} \end{array} $	[2] [3]	-	14.4	mJ

Symbol	Parameter	Conditions		Min	Max	Unit
I <sub>AS</sub>	non-repetitive avalanche current	$V_{sup} ≤ 60 V; V_{GS} = 10 V; T_{j(init)} = 25 °C;$ R <sub>GS</sub> = 50 Ω; Fig. 5	[2] [3] [4]	-	16.2	A

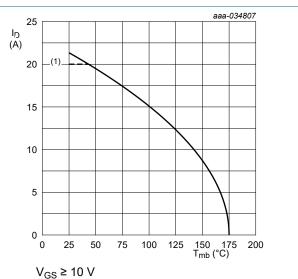
[1] 20 A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

[2] Single-pulse avalanche rating limited by maximum junction temperature of 175 °C.

- [3] Refer to application note AN10273 for further information.
- [4] Protected by 100% test.

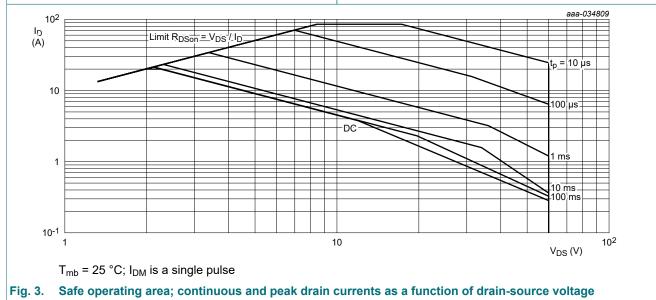


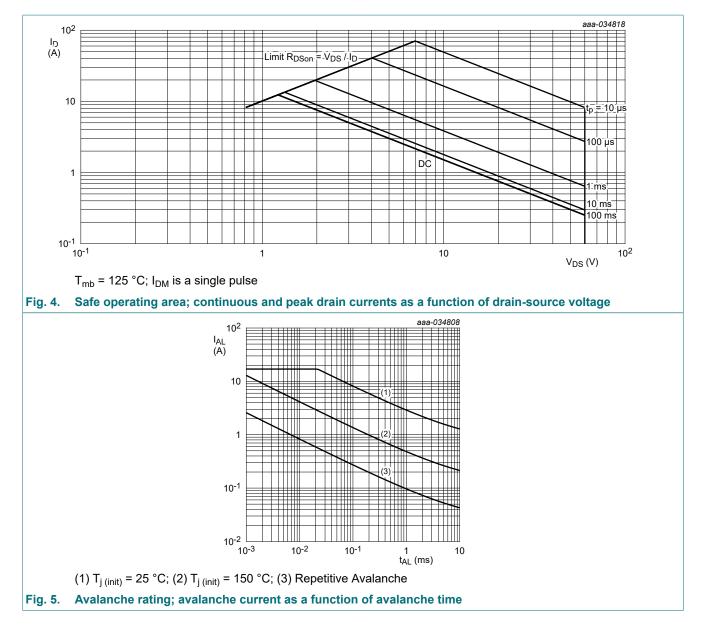




(1) 20 A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

## Fig. 2. Continuous drain current as a function of mounting base temperature

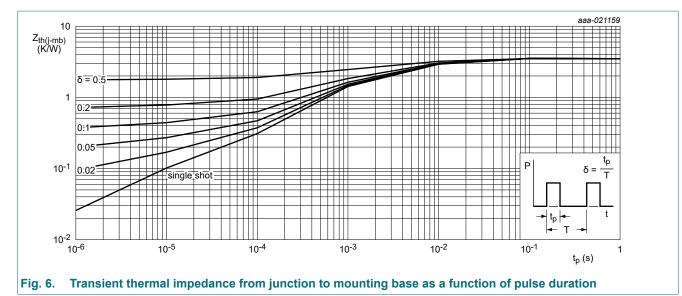




### 9. Thermal characteristics

#### Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R <sub>th(j-mb)</sub>	thermal resistance from junction to mounting base	<u>Fig. 6</u>	-	3.1	3.33	K/W

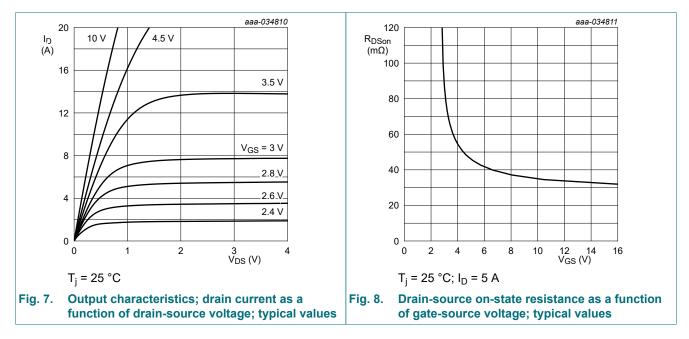


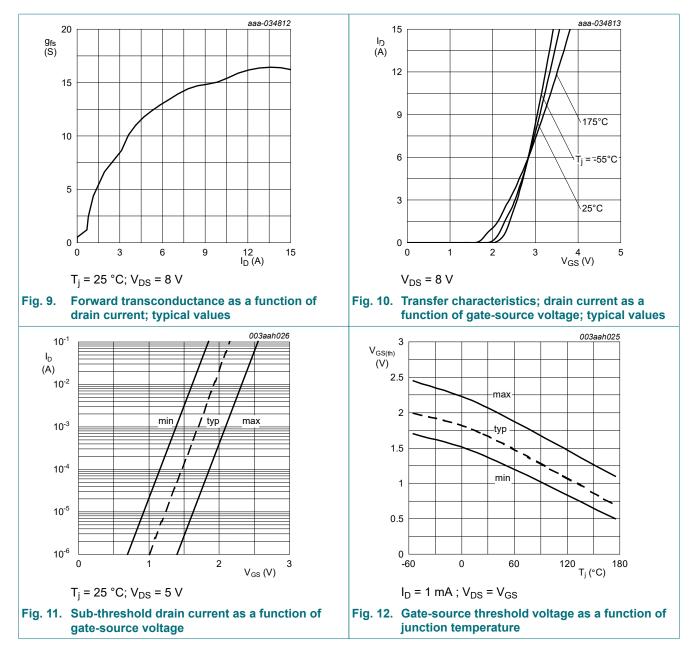
## **10. Characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	cteristics	· · ·				
V <sub>(BR)DSS</sub>	drain-source	I <sub>D</sub> = 250 μA; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C	60	66	-	V
	breakdown voltage	I <sub>D</sub> = 250 μA; V <sub>GS</sub> = 0 V; T <sub>j</sub> = -40 °C	-	62.7	-	V
		I <sub>D</sub> = 250 μA; V <sub>GS</sub> = 0 V; T <sub>j</sub> = -55 °C	54	61.7	-	V
V <sub>GS(th)</sub>	gate-source threshold voltage	$I_D = 1 \text{ mA}; V_{DS}=V_{GS}; T_j = 25 \text{ °C}; Fig. 11; Fig. 12$	1.4	1.65	2.1	V
		I <sub>D</sub> = 1 mA; V <sub>DS</sub> =V <sub>GS</sub> ; T <sub>j</sub> = -55 °C; <u>Fig. 12</u>	-	-	2.45	V
		I <sub>D</sub> = 1 mA; V <sub>DS</sub> =V <sub>GS</sub> ; T <sub>j</sub> = 175 °C; Fig. 12	0.5	-	-	V
I <sub>DSS</sub>	drain leakage current	V <sub>DS</sub> = 60 V; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	0.003	1	μA
		V <sub>DS</sub> = 60 V; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 175 °C	-	10	500	μA
I <sub>GSS</sub> gate leakage curren	gate leakage current	V <sub>GS</sub> = 10 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	2	100	nA
		V <sub>GS</sub> = -10 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	2	100	nA
R <sub>DSon</sub>	drain-source on-state resistance	V <sub>GS</sub> = 10 V; I <sub>D</sub> = 5 A; T <sub>j</sub> = 25 °C; <u>Fig. 13</u>	24.5	35	43.8	mΩ
		V <sub>GS</sub> = 10 V; I <sub>D</sub> = 5 A; T <sub>j</sub> = 105 °C; <u>Fig. 14</u>	37.3	55.7	71	mΩ
		V <sub>GS</sub> = 10 V; I <sub>D</sub> = 5 A; T <sub>j</sub> = 125 °C; <u>Fig. 14</u>	41	61	79	mΩ
		V <sub>GS</sub> = 10 V; I <sub>D</sub> = 5 A; T <sub>j</sub> = 175 °C; Fig. 14	51	76	100	mΩ
		V <sub>GS</sub> = 4.5 V; I <sub>D</sub> = 5 A; T <sub>j</sub> = 25 °C; <u>Fig. 13</u>	35	50	66.7	mΩ
		V <sub>GS</sub> = 4.5 V; I <sub>D</sub> = 5 A; T <sub>j</sub> = 105 °C; Fig. 14	52	77	106	mΩ
		V <sub>GS</sub> = 4.5 V; I <sub>D</sub> = 5 A; T <sub>j</sub> = 125 °C; Fig. 14	57	84.5	117.5	mΩ
		V <sub>GS</sub> = 4.5 V; I <sub>D</sub> = 5 A; T <sub>j</sub> = 175 °C; Fig. 14	69	105	148	mΩ
R <sub>G</sub>	gate resistance	f = 1 MHz; T <sub>i</sub> = 25 °C	-	1.82	-	Ω

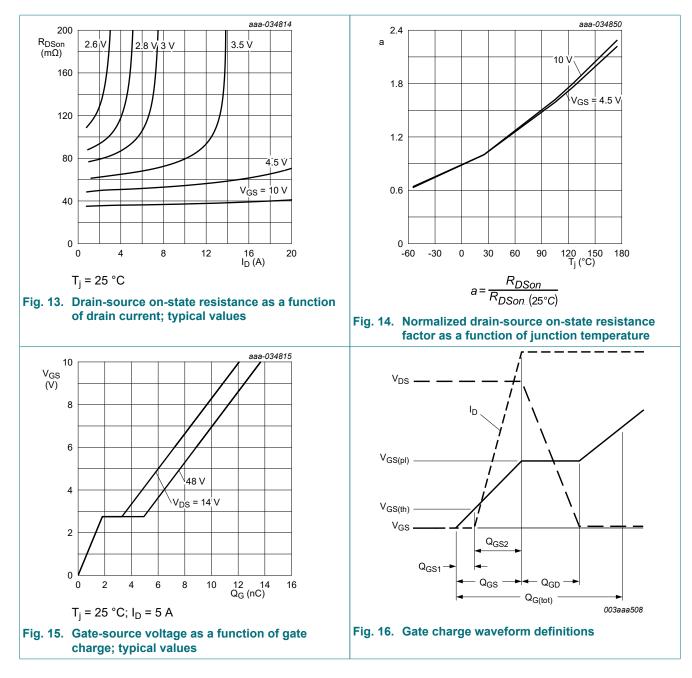
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Dynamic ch	naracteristics						
Q <sub>G(tot)</sub> total gate charge	total gate charge	$I_D$ = 5 A; V <sub>DS</sub> = 48 V; V <sub>GS</sub> = 4.5 V; T <sub>j</sub> = 25 °C; <u>Fig. 15</u> ; <u>Fig. 16</u>		-	7	10	nC
	I <sub>D</sub> = 5 A; V <sub>DS</sub> = 48 V; V <sub>GS</sub> = 10 V; T <sub>j</sub> = 25 °C; <u>Fig. 15; Fig. 16</u>		-	14	19	nC	
Q <sub>GS</sub>	gate-source charge	$I_D = 5 \text{ A}; V_{DS} = 48 \text{ V}; V_{GS} = 4.5 \text{ V};$		-	1.8	2.7	nC
Q <sub>GD</sub>	gate-drain charge	T <sub>j</sub> = 25 °C; <u>Fig. 15; Fig. 16</u>		-	3.1	6.2	nC
C <sub>iss</sub>	input capacitance	V <sub>DS</sub> = 25 V; V <sub>GS</sub> = 0 V; f = 1 MHz; T <sub>j</sub> = 25 °C; <u>Fig. 17</u>		-	653	915	pF
C <sub>oss</sub>	output capacitance			-	76	91	pF
C <sub>rss</sub>	reverse transfer capacitance			-	46	63	pF
t <sub>d(on)</sub>	turn-on delay time	$V_{DS} = 48 \text{ V}; \text{ R}_{L} = 9.6 \Omega; \text{ V}_{GS} = 5 \text{ V};$		-	5	-	ns
t <sub>r</sub>	rise time	$R_{G(ext)} = 5 \Omega; T_j = 25 °C$		-	9	-	ns
t <sub>d(off)</sub>	turn-off delay time			-	10	-	ns
t <sub>f</sub>	fall time	-		-	8	-	ns
9 <sub>fs</sub>	transfer conductance	V <sub>DS</sub> = 8 V; I <sub>D</sub> = 5 A; T <sub>j</sub> = 25 °C; <u>Fig. 9</u>		-	12.3	-	S
Source-dra	in diode						
V <sub>SD</sub>	source-drain voltage	I <sub>S</sub> = 5 A; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C; <u>Fig. 18</u>		-	0.83	1	V
t <sub>rr</sub>	reverse recovery time	I <sub>S</sub> = 5 A; dI <sub>S</sub> /dt = -100 A/µs; V <sub>GS</sub> = 0 V;		-	23	-	ns
Q <sub>r</sub>	recovered charge	V <sub>DS</sub> = 30 V; T <sub>j</sub> = 25 °C; <u>Fig. 19</u>	[1]	-	22	-	nC

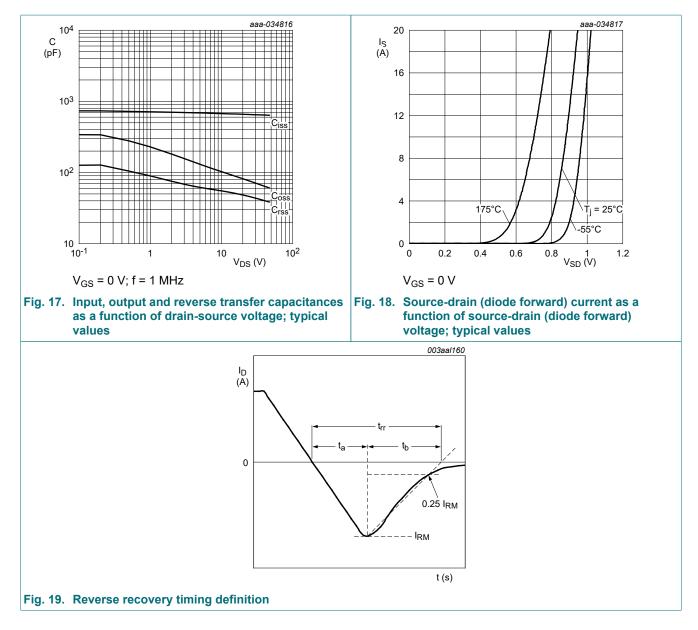
[1] includes capacitive recovery



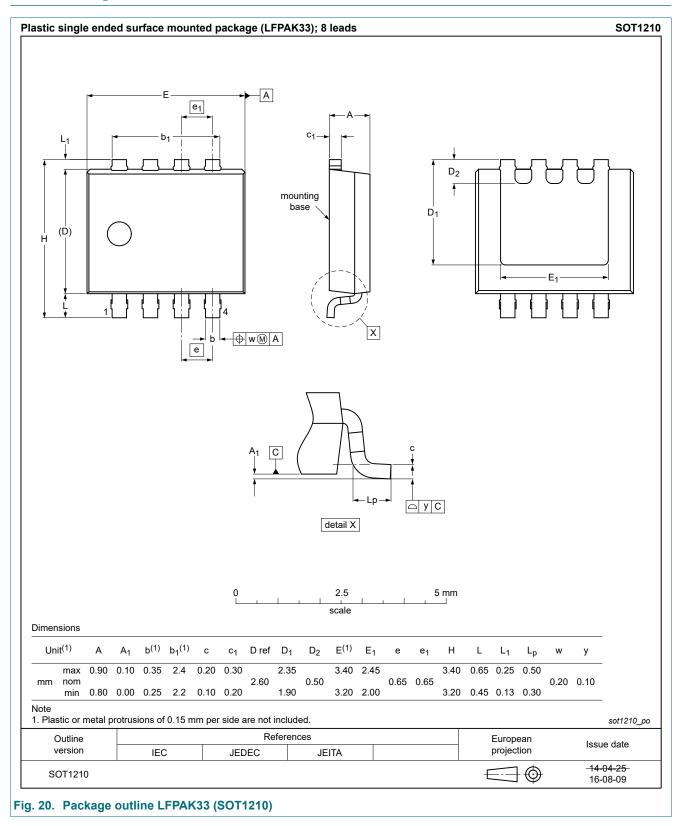


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## 11. Package outline



## 12. Legal information

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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